

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	41	semiconductor and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film)) and ((silicon adj carbide) or ("Si:C")) and @ad<="20040423"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/31 20:19
S1	1603	(438/149).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/28 14:13
S2	201	"438"/\$.ccls. and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:15
S3	291	"257"/\$.ccls. and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:16
S4	44	"257"/\$.ccls. and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film)) and ((silicon adj carbide) or ("Si:C"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:16
S5	27	"438"/\$.ccls. and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film)) and ((silicon adj carbide) or ("Si:C"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:18
S6	50	semiconductor and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film)) and ((silicon adj carbide) or ("Si:C"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:17
S7	21	"438"/\$.ccls. and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film)) and ((silicon adj carbide) or ("Si:C")) and @ad<="20040423"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:18

S8	35	"257"/\$.ccls. and ((silicon adj on adj insulator) or ("SOI")) and ((silicon adj germaninum) or ("SiGe")) and (strain\$4 adj (layer or film)) and ((silicon adj carbide) or ("Si:C")) and @ad<="20040423"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/28 14:18
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